Section of pharmacology and Toxicology of the Moscow Society of Physiologists, Biochemists and Pharmacologists. Farm. i toks. 19 no.6:58-59 N-D '56. (MIRA 10:2) (PHARMACOLOGY) (POISONS)

RAYSKINA, M.H.; SAMOYLOVA, Z.T.

Effects of I.P.Pavlov's accelerator nerve on coronary circulation. Biul.eksp.biol.med. 42 no.6:3-7 Je '56. (MLRA 9:9)

1. Iz kafedry patologicheskoy fiziologii TSentral*nogo instituta usovershenstvovaniya vrachey (dir. V.P.Lebedeva) i laboratorii patologicheskoy fiziologii (zav. - prof. V.V.Parin) Instituta terapii AMN SSSR, Moskva. Predstavlena deystvitel*nym chlenom AMN SSSR A.L.Myasnikovym.

(HEART, innervation

Pavlov's accelerator nerve, eff. of stimulation on coronary circ. in dogs, ECG)

(ELECTROCARD IOGRAPHY,

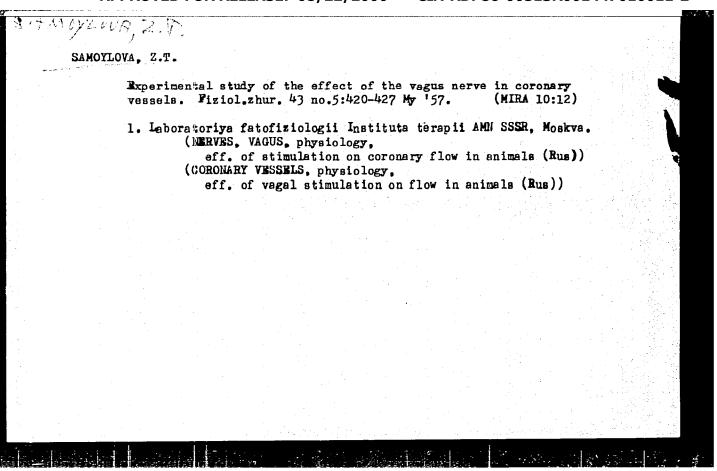
eff. of stimulation of Pavlov's accelerator nerve on coronary circ. in dogs)

SAMOYLOVA, Z.T.

Effect of narcotics on renal circulation in healthy dogs and in dogs with experimental hypertension. Biul.eksp.biol.med. 42 no.6:45-48
Je 156. (MLRA 9:9)

1. Iz laboratorii patologicheskoy fiziologii (zav. - prof. V.V.Parin) Instituta terapii (dir. - deystvitel'nyy chlen AMN SSSR A.L.Myasnikov) AMN SSSR, Moskva. Predstavlena deystvitel'nym chlenom AMN SSSR A.L.Mysnikovym.

(KIDNEYS, blood supply
in hypertensive & normal dogs, eff. of anesthetics)
(HYPERTENSION, exper.
eff. of anesthetics on renal blood supply in dogs)
(ANESTHETICS, eff.
on renal blood supply in hypertensive & normal dogs)



MENTOVA, V.N.; SAMOYLOVA, Z.T.; SMAZHNOVA, N.A. Hypotensive and adrenolytic action of sympatholytin. Trudy Vses. ob-va fiziol., biokhim. i farm. 4:149-156 '58.

(MIRA 14:2)

1. Institut terapii AMN SSSR. Direktor instituta prof. A.L. Myasnikov. (SYMPATHOLYTICS)

	Chang	main f		Change in the reflex reaction of the vessels of the extremities to									
	adren Gip.b	aline :	and according 5:1:	flex react tylcholin 12-122 '58 S (ANATOM: ADRENALIN	ne in e 8. Y)) (RE	rperime	ntal	hyperte PERTENS	ension	in do	os to ogs. 13:5)	
						•							
								1					
				• •						•			
					. ******								7-2
											-		

Pharmacology and texicology section of the Moscow Society of Physiologists, Biochemists and Pharmacologists. Farm, 1 toks. 21 no.2:95 Mr-Ap '58 (MIRA 11:6) (PHARMACOLOGY)

SAMOYLOVA, Z.T.

Effect of aprophene and diprophene on coronary circulation in experimental myocardial infarct [with summary in English].

Farm. i toks. 21 no.4:16-23 J1-Ag 158 (MIRA 11:11)

Report on congresses, conferences and society meetings, Farm, i toke 21 no.6:84-91 H-D.*58.

(PHARMACOLOGY)

(PHARMACOLOGY)

SAMOYLOVA, Z.T. (Moskva)

Result of prolonged cholesterol feeding of cats under various experimental conditions. Pat. fiziol. i eksp. terap. 3 no.3:47-52 My-Je '59. (MIRA 12:7)

l. Iz patofiziologicheskoy laboratorii Instituta terapii AMN SSSR (dir. - deystvitel'nyy chlen AMN SSSR prof. A.L. Myasnikov).

(ARTERIOSCIEROSIS, experimental, cholesterol-induced in cats exposed to various exper.

conditions (Rus))
(CHOLESTEROL, eff.

exper. arteriosclerosis in cats exposed to various exper. conditions (Rus))

SAMOYLOVA, Z.T.; RAYSKINA, M.Ye. (Moskva)

Hemobarostat an apparatus for maintaining arterial pressure at a constant level. Pat.fiziol. i eksp.terap. 3 no.6:65-68 N-D 159.

(MIRA 13:3)

1. Iz laboratorii patologicheskoy fiziologii Instituta terapii AMN SSSR (direktor - deystvitel'nyy chlen AMN SSSR prof. A.L. Myasnikov) 1 kafedry patofiziologii (zaveduyushchiy - chlen-korrespondent AMN SSSR prof. P.D. Gorizontov) TSentral'nogo instituta usovershenstvovaniya vrachey.

(CARDIOLOGY equip. & supplies)
(BLOOD PRESSURE)

SAMOYLOVA, Z.T.

Experimental data on the effect of pentamine on coronary circulation in acute disorders of cardiac blood supply [with summary in English]. Farm. i toks. 22 no.1:52-58 Ja-F '59. (MIRA 12:4)

1. Laboratoriya patofiziologii Instituta terapii AMN SSSR (dir. - deystvitel'nyy chlen AMN SSSR A.L. Myasnikov).

(PENDIOMIDE, effects,
on coronary circ. (Rus))

(CORONARY VESSEIS, eff. of drugs on,
pendiomide (Rus))

MENTOVA, V.N.; SAMOYLOVA, Z.T.

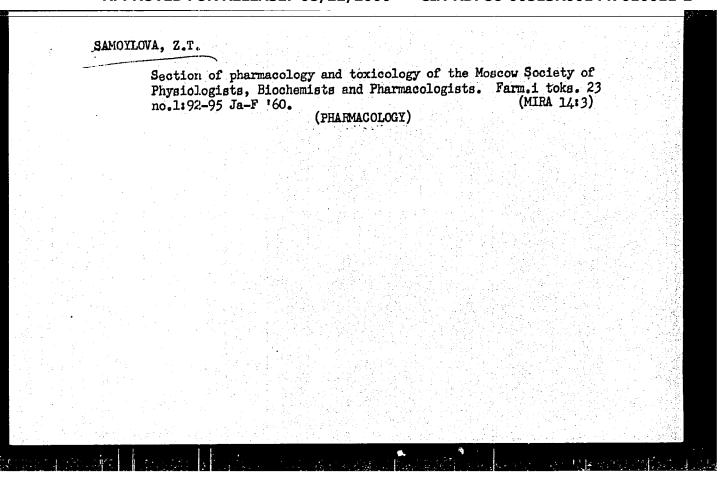
Effect of dioquine on the arterial pressure of dogs with experimental hypertension. Khim, i med. no.15:125-130 '60. (MIRA 15:1)

1. Iz patofiziologicheskoy laboratorii Instituta terapii AMN SSSR. (dir. - deystvitel'nyy chien AMN SSSR prof. A.L.Myasnikov). (BLOOD PHESSURE) (HYPERTENSION) (DIOQUINE-PHYSIOLOGICAL EFFECT)

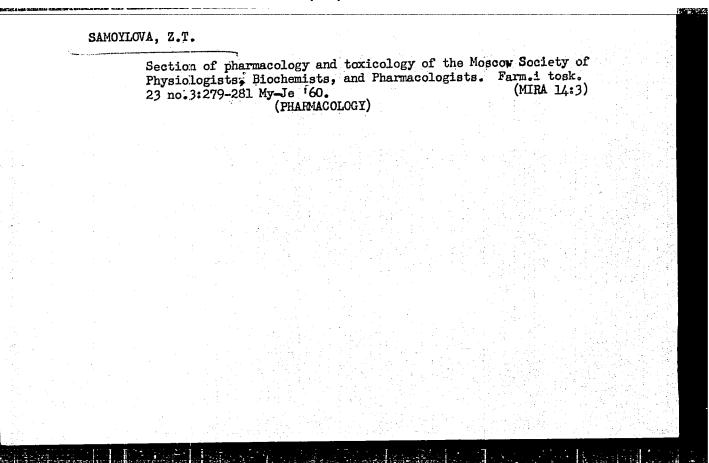
MENTOVA, V.N.; SAMOYLOVA, Z.T. (Moskva)

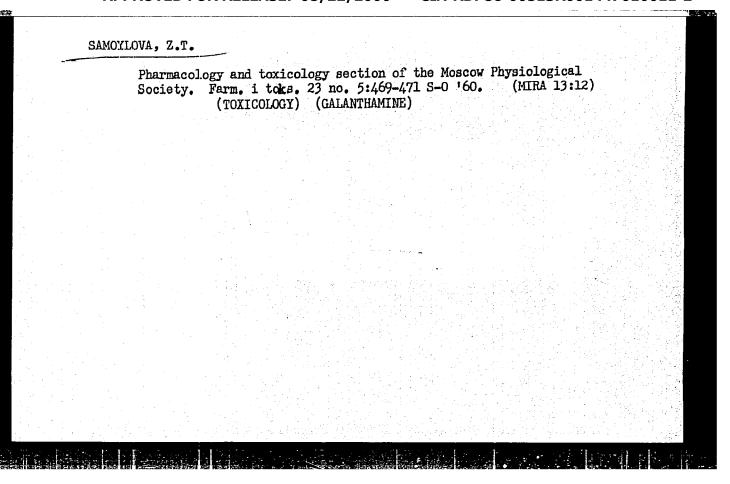
Dynamics of the development of cardiovascular disorders with changes in blood lipids during the production of experimental atherosclerosis in dogs. Pat.fiziol.i eksp.terap. 4 no.4:32-38 Jl-Ag '60. (MIRA 14:5)

1. Iz Instituta terapii (dir. - deystvitel'nyy chlen AMN SSSR prof. A.L.Myasnikov) AMN SSSR. (ARTERIOSCLEROSIS) (LIPIDS)



	Section of pharmacology and toxicology of the Moscow Society of Physiologists, Biochemists, and Pharmacologists. Farm.i toks. 23 no.2:186-k87 Mr-Ap '60. (MIRA 14:3) (PHARMACOLOGY)	
	기 - 그리는 그리는 사람들은 기를 가는 것이 되었다. 그런 사람들은 사람들은 사람들은 사람들은 사람들은 사람들은 사람들은 사람들은	
	마이트 보고 있는 것이 되었다. 그런	
rs.		





Effect of chloracizine on the cardiovascular system. Farm.1 toks. 23 no.6:503-508 N-D '60. 1. Institut terapii AMN SSSR (dir. - deystvitel'nyy chlen AMN SSSR A.L.Myasnikov). (PHENOTHIAZINE) (PARASYMPATHOLYTICS) (CARDIOVASCULAR SYSTEM)

SAMOYLOVA, Z.T.; TANK, L.I.

Brief news. Farm.i toks. 23 no.6:562-563 N-D'60. (MIRA 1413)

1. Sekretar' sektsii farmakologii i toksikologii Leningradskogo obshchestva fiziologov, blokhimikov i farmakologov imeni I.M.

Sechenova (for Tank).

(PHARMACOLOGY)

RAYSKINA, M.Ye.; SAMOYLOVA, Z.T. (Moskva)

Nervous influences on the blood coagulation rate in experimental arteriosclerosis. Pat.fiziol.i eksp.terap. 5 no.1:40-46 Ja-F '61. (MIRA 14:6)

1. Iz kafedry patologicheskoy fiziologii (zav. - chlen-korrespondent ANN SSSR prof. P.D.Gorizontov) TSentral nogo instituta usovershenstvovaniya vrachey.

(ARTERIOSCLEROSIS) (BLOOD—COAGULATION)

(NERVOUS SYSTEM, SYMPATHETIC)

SAMOYLOVA, Z.T. (Moskva)

Effect of vitamin K (vikasol) on the development of arteriosclerosis in rabbits. Pat.fiziol. i eksp. terap. 5 no.3:33-38 My-Je '61.

(MIRA 14:6)

1. Iz laboratorii patofiziologii Instituta terapii (dir. - deystvitel'nyy chlen AMN SSSR prof. A.L. Myasnikov) AMN SSSR. (ARTERIOSCLEROSIS) (VITAMINS_K)

SAMOYLOVA, Z.T.; RYAZHENOV, V.V.

Effect of heparin on the coronary circulation. Farm.i toks. 24 no.1:66-70 Ja-F '61. (MIEA 14:5)

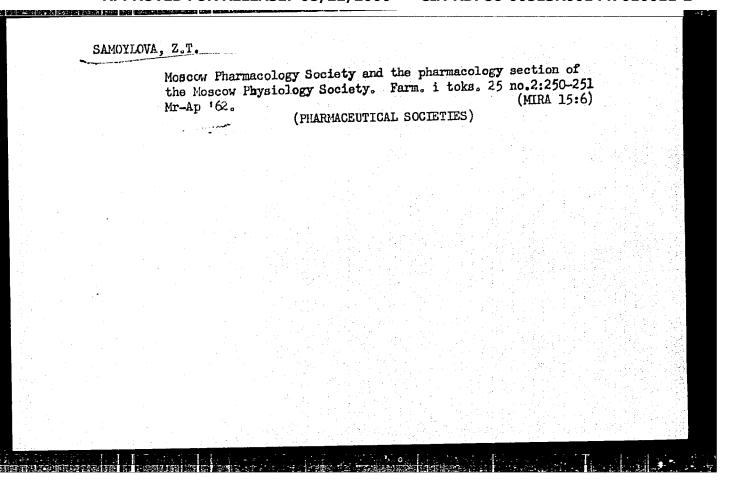
l. Institut terapii AMN SSSR (dir. - deystvitel'nyy chlen AMN SSSR prof. A.L.Myasnikov) i kafedra farmakologii farmatsevticheskogo fakul'teta (zav. - prof. M.M.Nikolayeva) I Moskovskogo ordena Lenina meditsinskogo instituta.

(CORONARY VESSEIS) (HEPARIN)

Moscow Pharmacological Society and the pharmacology section of the Moscow Physiological Society. Farm.i toks. 24 no.2:251-252 Mr-Ap '61. (MOSCOW-PHARMACOLOGICAL SOCIETIES)

	Moscow Pharmacological Society and the section on pharmacology of the Moscow Physiological Society. Farm. i toks. 24 no.5:637-638 (MIRA 14:10)
	S-0 '61. (MOSCOWPHARMACEUTICAL SOCIETIES)
	그는 그는 것이 있다고 되는 그들이는 이 관심수는 원리를 받는 그리고 하는데 한 선생님이 그리고만 될 때문에
	그 그 그 그 그는 그는 이 이 이 있는 것이 되었다. 그런 그 그는 이 이 모든 것이 되는 것이라고 그렇다.
	그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그
	그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그
	그 그 그 그는 그 그 그 그 그 그 그 그들은 그 생생님이 하는 그 그 그 그 사람들이 그 사람들은 그 그 그를 모든 모든 생활하다.
	그 그 그 그 그 그 그 그 그 그는 그는 그는 이 눈을 보고 보는 데 하는 그 그 그 그 그 그 그 그 그를 했다. 그 그를 달아왔는 것 같다.
	그 그 그 그 그 그 그 그 그는 그는 그 중에 가장 하는 그는 그는 사람들이 가셨다면 하는 것이 많은 것이 함께 없는 것이 함께 다른 것이다.
	그 그는 그 그 그 그 그 그 그 그는 아이들은 사람들이 되는 그 그 그 그 그 그 그를 가지 않는 것이 되는 것이다.
	그 그 그 그 그 그는 그 이 이 그는 그는 그 그는 그 그는 그는 그는 그는 그를 가지 않는 것이 되었다. 학생
	그는 그 그는 그는 그는 그는 사람들이 가장 그 그는 그는 그는 그를 가지 않는 그를 살았다. 낮은
	1997年 - 1997年 - 1997年 - 1998年 - 1998年 - 1998年 - 1997年 -
	그 그 그는 그는 그는 그 사람들이 그리는 활근 그리는 그는 그는 그릇 경에 그는 맛이라면 가족
	그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그 그
•	그는 그는 사람들은 그리고 사람이 하다면 살라고 있는 것이 가는 사람들이 밝힌 방법을 가려 살아왔다고요?
	그 이 그는 그 그 그 아이는 이 가장한 것이 되는 것이 되었습니다. 그리고 살아 바꿨어가 없는 사람들이 화가지 않다.
	그
	그는 그 그는 그는 그는 그는 그는 일반이 되었다. 사람들은 생각이 보고 있다는 보장이 불편을 하는 것이 되었다. 그는 사람이 없는 것이 없는 것이 없는 것이 없는 것이 없다. 그는 것이 없는 것이 없는 것이 없는 것이 없는 것이 없다면 없다.
	이 가게 하는 그 사람들이 하는 그렇게 가장한 사람들이 얼마나 있다. 그를 가장 화장한 점점을 하는 것이 없다.
	사람들은 현실 사람들은 사람들은 사람들은 사람들이 가는 경기에서 선택을 받아 다음 생생님께 되었다.
	는 하는 일이 되었는데 보고 있는데 하는데 사람들이 되었다면 하는데 보다 되었다. 그런데 보다 보다 보다 보다는데 보다 되었다면 보다 되었다면 하는데 보다 되었다면 보다 되었다면 보다 되었다면 보다 보다 되었다면 보니요. 그렇지 되었다면 보다 되었다면 보다 되었다면 보니요. 되었다면 보다 되었다면 보다 되었다면 보다 되었다면 보다 되었다면 보다 되었다면 보니요. 되었다면 보다 되었다면 보니 되었다면 보다 되었다면 보다 되었다면 보다 되었다면 보다 되었다면 보니 되

	Effect of sodium nitrite, nitroglycerin and papaverine on renal Effect of sodium nitrite, nitroglycerin and papaverine on renal circulation in experimental atherosclerosis. Farm. i toks. 25 no.1: (MIRA 15:4) 38-43 Ja-F '62.								
	38-43 Ja-F '62. 1. Institut terapii AMN SSSR (dir deystvitel'nyy chlen AMN SSSR A.L.Myasnikov). (KIDNEYS-BLOOD SUPPLY) (ARTERIOSCLEROSIS) (KIDNEYS-BLOOD SUPPLY) (SODIUM NITRITE) (NITROGLYCERIN) (PAPAVERINE)								
:									



"APPROVED FOR RELEASE: 08/22/2000 CIA-RDF

IN CHARLES STORY OF THE PERSON NAMED IN COLUMN 1

CIA-RDP86-00513R001447010011-2

SAMOYLOVA, Z.T.

Effect of pharmacological preparations on coronary circulation under conditions of chronic tests on dogs with experimental atherosclerosis. Farm.i toks. 24 no.6:682-686 N-D '61. (MIRA 15:11)

1. Institut terapii AMN SSSR (dir. - deystvitel'nyy chlen AMN SSSR

1. Institut terapii Arm Ober (CARDIOVASCULAR AGENTS) (ARTERIOSCLEROSIS)

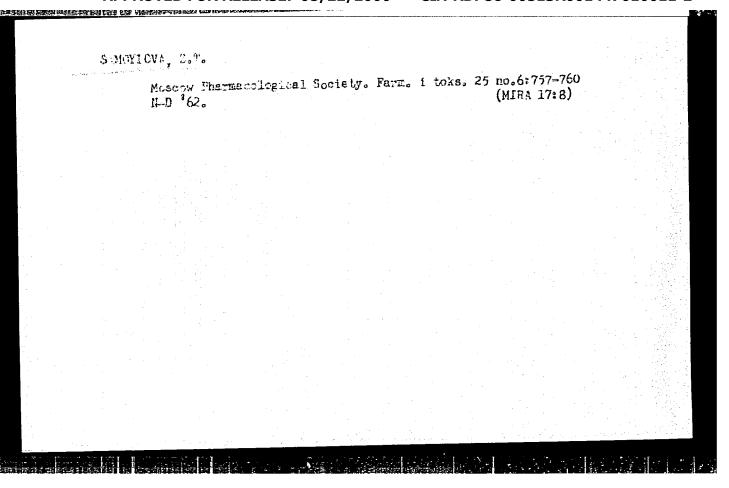
(CARDIOVASCULAR AGENTS)

SAMOYLO	Moscow Pharmacological Society and the Section on Pharmacology of the Moscow Physiological Society. Farm.i toks. 24 no.6:755-758 (MIRA 15:11) N-D '61. (PHARMACEUTICAL SOCIETIES)	

SAMOYLOVA, Z.T.; SMIRNOVA, S.; FROLOV, S.; TANK, L.I.; ZAPADNYUK, V.I.

Brief news. Farm. i toks. 25 no.4:502-508 Jl-Ag '62.

(MIRA 17:10)



CIA-RDP86-00513R001447010011-2

RAYSKINA, M. Ye.; KHODAS, M. Ya.; SAMOYLOVA, Z.T.

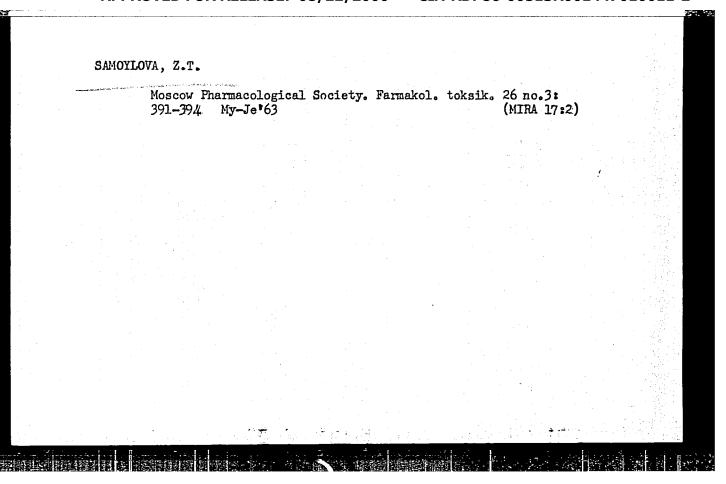
Significance of blood supply disorders of the heart in the mechanism of death during the acute stage of myocardial infarct. Kardiologiia 3 no.4845-50 Jl-Ag 63 (MIRA 17:3)

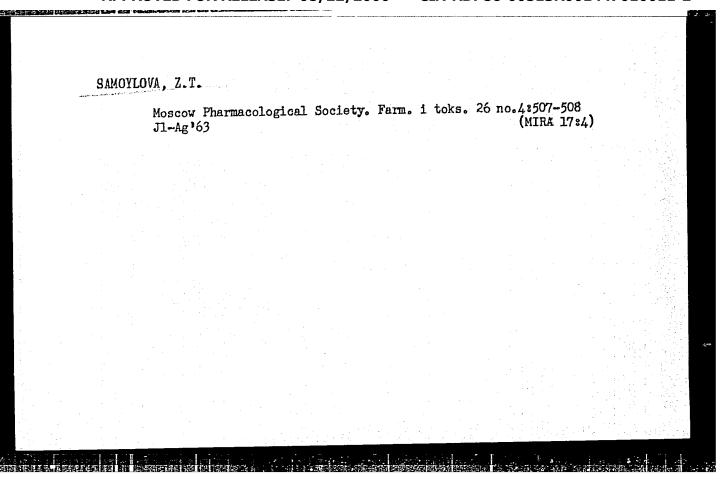
1. Iz kafedry patofiziologii (zav. - prof. S.M. Leytes) TSentral nogo instituta usovershenstvovaniya vrachey.

KHODAS, M.Ya. (Moskva); SHIMELIOVICH, L.B. (Moskva); RAYSKINA, M.Ye. (Moskva); SAMOYLOVA, Z.T. (Moskva)

Determination of oxygen tension in the myocardium by polarography. Pat. fiziol. i eksp. terap. 7 no.2:73-76 Mr-Ap'63. (MIRA 16:10)

1. Iz kafedry patofiziologii (zav. - prof. S.M. Leytes) TSentral'nogo instituta usovershenstvovaniya vrachey.
(HEART—MUSCLE) (OXYGEN IN THE BODY)





"APPROVED FOR RELEASE: 08/22/2000 CI

CIA-RDP86-00513R001447010011-2

RAYSKINA, M.Ye.; SAMOYLOVA, Z.T.; KHODAS, M.Ya.

建设设置的设计区域设计区域 100 时间的过去时间的 100 000 000 000

Importance of disorders in the blood supply of the heart in the death mechanism during the acute stage of myocardial infarction. Trudy Inst. klin. i eksper. kard. AN Gruz. SSR 8:419-422 163.

l. Kafedra patolfiziologii TSentral'nogo instituta dlya usovershenstvovaniya vrachey, Moskva.

SAMOYLOVA, Z.T.; RAYSKINA, M.Ye.; KHODAS, M.Ya. (Moskva)

Significance of disorders of the heart blood supply in the mechanism of death from myocardial infarct in dogs with mechanism of death from myocardial infarct in Action (MIRA 17:9) 22-26 Jl-Ag '63.

1. Iz kafedry patofiziologii (zav.- prof. S.M. Leytes)

TSentral'nogo instituta usovershenstvovaniya vrachey.

Samovicus, Release Formacological Society. Farm. 1 toks. 26 no.22250-251 (MIRA 17:8)		أة إنجينيين فيعمين بيد مويد	10VA, So To	gical Societ	y. Farm	o i toksa	25	(MIRA 17: 6	5)	
			Mr-Ap 163.							
	·									

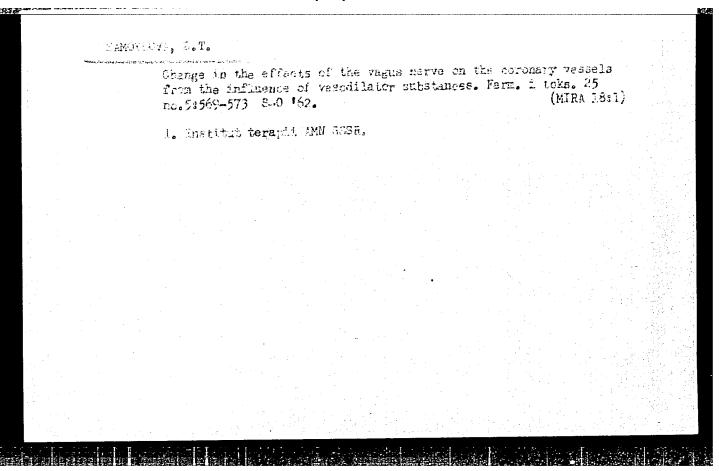
•	والمواج وهلتان بحداث فالمعطب محاد			estati estati	offec.	t.s of	the V	gus narve vesodilate	on the	COLOURI	y		
		Cha ver Fai	inge i sels rm. i	under toks.	the in 25 no	nflue .5:56	ence of 69-573	vesodilate S-0 '64.	or subs	(Auges.	(MIRA	18:1)	
		1.	Insti	tut to	erapii	AMN	SSSR.						
												j.	
		-											
												le situat Aggisti	
													Å.

RAYSKINA, M.Ye.; SAMOYLOVA, Z.T.; KHODAS, M.Ya.

Effect of acetylcholine on the oxygen balance of the heart. Farm. i toks. 27 no.4:451-454 J1-Ag 164.

(MIRA 17:11)

l. Kafedra patofiziologii (zav. - prof. S.M. Leytes) TSentralinogo instituta uscvershenstvovaniya vrachey, Moskva.



RAYSKINA, M.Te.; SAMDYLOVA, Z.T.; KHODAS, M.Ya.

Effect of adrenaline, noradrenaline and acetylcholine on the oxygen balance of the heart following a ligation of the coronary artery. Pat. fiziol. i eksp. terap. 9 no.3:16-20. My-Je 165. (MIRA 18:9)

1. Kafedra patologicheskoy fiziologii (zav.- prof. S.M. Leytes)
TSentral nogo instituta usovershenstvovaniya vrachey, Moskva.

"APPROVED FOR RELEASE: 08/22/2000

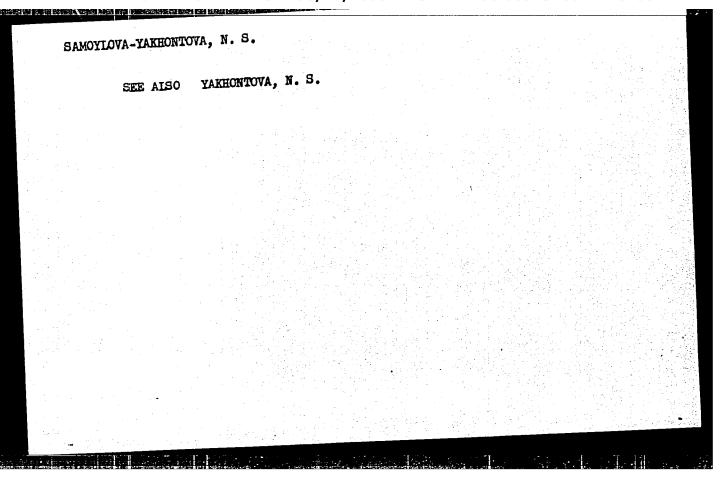
CIA-RDP86-00513R001447010011-2

YANISHEVSKAYA, M.N.; DUBOVITSKAYA, N.K.; KLYUCHAREVA, T.Ye.; MITRIKINA, P.Ye.; PEKSHEVA, M.N.; SAMOYLOVA, Z.Ye.; TYUNEYEVA, G.A.

Difficulties in diagnosing some atypical dysenterial bacteria. Med. zhur. Uzb. no.2:20-22 F '62. (MIRA 15:4)

1. Iz kafedry mikrobiologii (zav. - prof. P.F.Samsonov) Tashkentskogo gosudarstvennogo meditsinskogo instituta i laboratoriy gorodskoy i rayonnykh sanitarno-epidemiologicheskikh stantsiy Tashkenta.

(SHIGEILA) (DYSENTERY)



SAMOYLOVA-YAKHONTOVA, N.3.

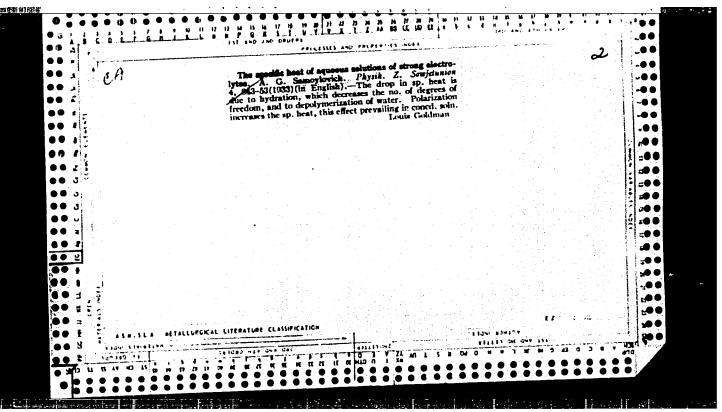
Minor Planets (1962). Biul. Inst. teor. astron. 9 no. 6:379-387 (MIRA 17:9)

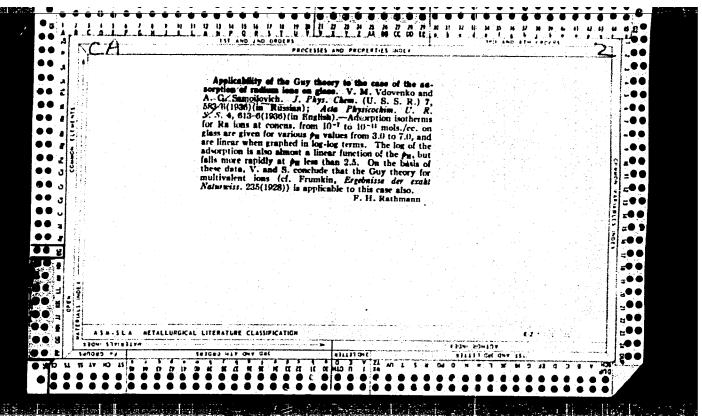
•	Minor	planets,	1963.	Biul.	Inst.	teor.	astron.	10 no.3:17	3-180 (MIRA 18:8)
					144 11 3 1 421 11 1 1 1 1 2 1					

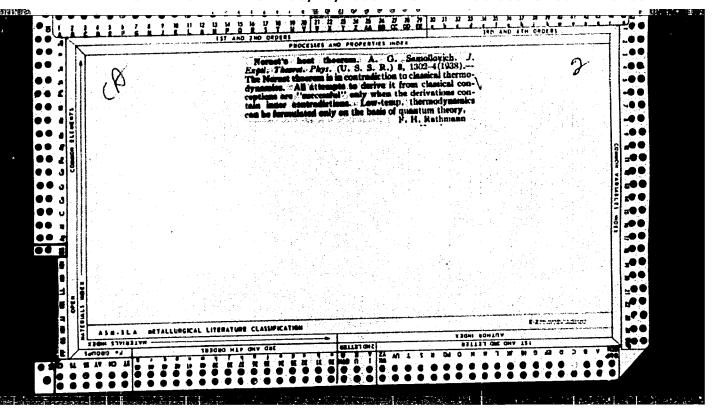
GRAKHOVSKIY, R.; SAMOYLOVICH, A.

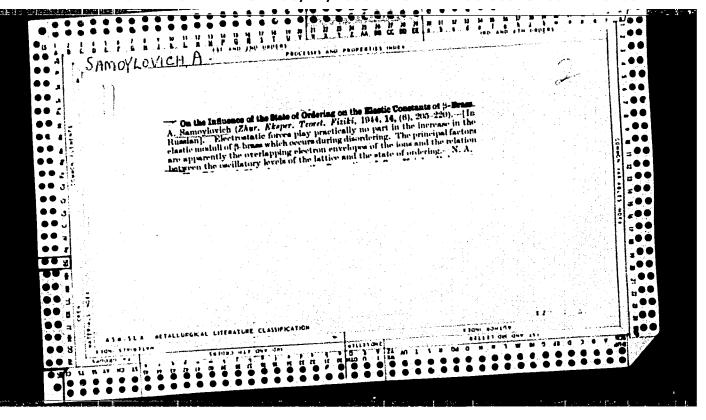
Automatic engine preheaters. Za rul. 18 no.2:22-23 F '60.
(MIRA 13:6)

1. Gosudarstvennyy soyuznett ordena Trudovogo Krasnogo Znameni
nauchno-issledovatel'skiy avtomobil'nyy i avtomotornyy institut.
(Automobiles-Cold weather operation)







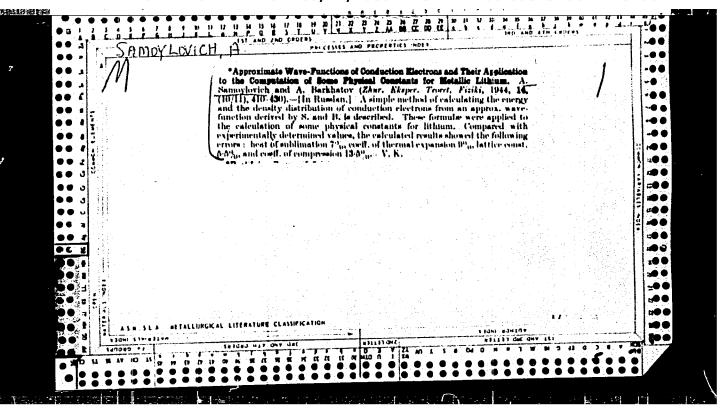


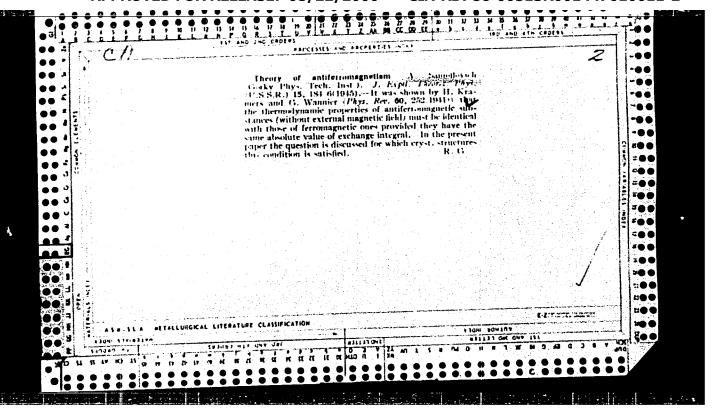
SAMOTIOVICH, A. G.

"Elastic Constants of Brass of Influences by the Ordered State of the Molecule," Zhur.

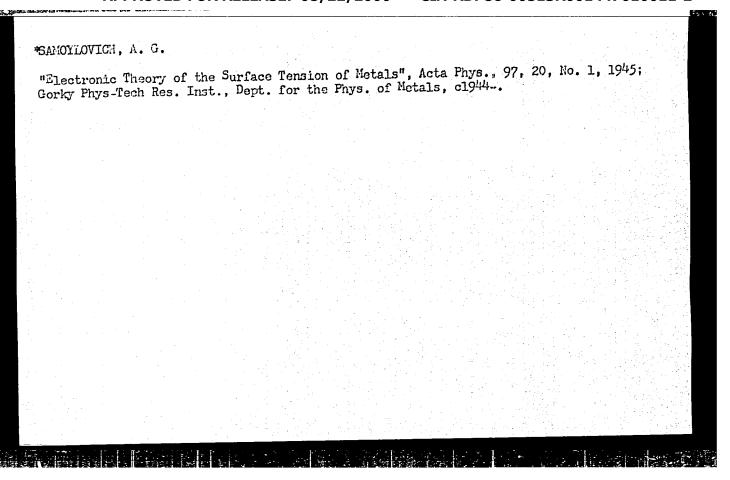
Eksper. i Teoret. Fiz., 14, No. 6, 1944; Dept. of Metallophysics, Gor'kiy Physico-Tech.

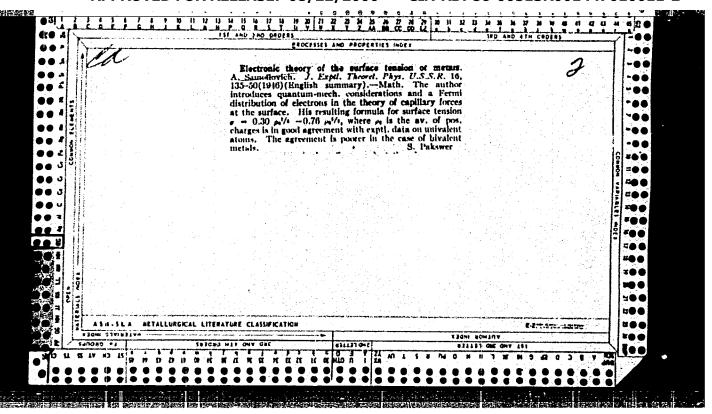
Inst., -1943-.

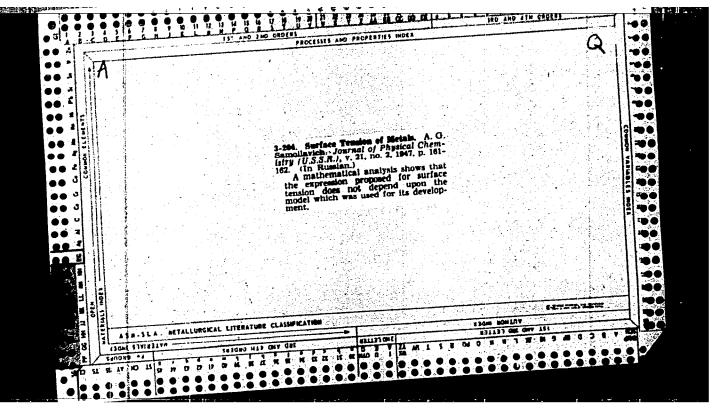




Mbr., Gor'kiy Scient							וטוב	
"Electronic Theory o	of Surface Ter	nsion in M	etals,"	DOK. AN	, 40,	70. A. 1	-777	
			-					
·								







SAMOTIOVICH, A. G.

"Review of P. G. Bergman's Book 'Introduction to the Theory of Relativity'." USPEKHI FIZ.

NAUK, 35, No. 4, 1948;

CA

9

Theory of the surface tension of metals. A. G. Samu-L. Roych, Zhur. Fis. Khim. 23, 1127(1949).—Glauberman's theory (C.A. 43, 4901c) is criticized. J. J. B.

SAMOYLOVICH, A. G.

168T96

APPROVED FOR RELEASE: 08/22/2000 CIA-RDP86-00513R001447010011-2

USSR/Physics - Ferromagnetics Magnetism, GalvanoSep 50

"The Theory of Galvonomagnetic Phenomena in Ferromagnetics," A. G. Samoylovich, V. L. Kon'kov, Chernovits State U

"Zhur Eksper i Teoret Fiz" Vol XX; No 9, pp 783-786

Proposes method for constructing subject theory. Derives certain results by this method. Submitted 16 Jan 50.

168796

USSR/Electricity - Ferromagnetics Mar 52

"Additional Resistance of Ferromagnetic Matals,"
A. G. Samoylovich, V. A. Yakovlev, Chernovtsy
State U

"Zhur Eksper i Teoret Fiz" Vol XXII, No 3, pp 350355

Considers the influence of spontaneous magnetization of a ferromagnetic crystal upon its elec
resistance. Establishes thermal dependence of the
addnl resistance in a low temp range. Received
23 Oct 51.

SAMOYLOVICH, A.G.

USSR/Physics - Ferromagnetics

Mar 52

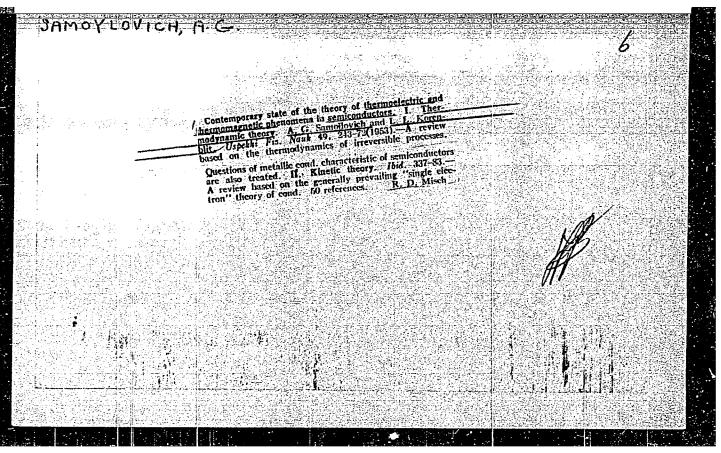
"Thermoelectric Phenomena in Ferromagnetics Near the Curie Temperature," A. G. Samoylovich, L. L. Korenblit, Chernovtsy State U

"Zhur Eksper i Teoret Fiz" Vol XXII, No 3, pp 360-366

Thermal dependence of Tompson and Peltier coeffs in ferromagnetics is computed near the Curie temp on the basis of s-d model created by Vonsovskiy (cf: "Zhur Eksper i Teoret Fiz" 16, 981, 1946). Received 9 Jun 51.

21,5177

SAMOYLOVICH, A.G. © 3839. Samollovich, A. C., Thermodynamics and statistical physics [Terrirodinamika i statisticheskaya fizikal, Moscow, Gosud, Izd. Tech. Teor. Lit., 1953, 439 pp. equilibrium statistical distributions leading to the identification An extended survey of the general analytical foundations of of the state sum, thermodynamic probability, and thermodythermodynamics and applied statistical mechanics is presented. namic temperature. The relations between the probability dis-The first part, entitled "Fundamental principles of thermotributions and the thermodynamic functions are emphasized. d, namics," provides an intensive and comprehensive mathemati-Part three, "Some applications of statistical physics to the I development of the first and second laws. The role of equiliinvestigation of classical systems," develops conventionally such innum states is clearly emphasized and sufficient flexibility is items as the virial equation of state for imperfect gases, the ovided to allow for many types of thermodynamic displace-Langevin function for dielectric polarization, second-order transiments and forces. The second law is introduced by a consideration phenomena, and the fundamentals of the thermodynamics of tion of Pfuffiam forms in the Caratheodory manner and is subsequently re-examined from the viewpoint of the Carnot cycle. electric and magnetic fields. The last part, "Ovantum statistica," develops the heat espacity The various relations among the thermodynamic functions are considered in relation to maximum work and equilibrium. The for a simple harmonic oscillator as occurring in metals and gases. The Fermi-Dirac and Bose-Einstein statistics are developed and thermodynamics of dielectrics, magnetism, and electrochemistry applied to the photon and electron gases. A general formulation is presented. Brief mention is made of the nature of irroversible is provided for the third law or Nerrat heat theorem. Throughout, processes in relation to the Chusius inequality. the treatment is largely analytical and consistent with other cur-The second part, "Fundamental principles of statistical rent treatments. Frequent reference is made to Engels, Marx, physics," provides a conventional systematic development of N. A. Hall, USA and Lenin.



SAMOYLOVICH, & G. and KORENBLIT, L.L.

"Present Status of the Theory of Thermoelectric and Thermomagnetic Phenomena of Semiconductors," Usp. Fiz. Nauk, 49, No.3, pp 337-383, 1953

Part II, kinetic theory. Part I appeared in issue No.2. State that the kinetic theory of thermoelectric ohenomena, in contrast to the thermodynamic bheory, proceeds from definite model representations concerning the structure of metals and other electrical conductors, and has as its main task the calculother the kinetic eds. Derive the distribution functions and kinetic eqs formally solve the kinetic eqs; generalize the laws of elec conductivity in the kinetic theory; derive the free path of electrons and the kinetic eqs in the high-temp case; discuss thermoelec phenomena in univalent metals as high temps, equilibrium of electrons in semiconductors, thermoelectric phenomena in memiconductarors with a tomic lattice and in ionic semiconductors; derive distribution function in case of seak magnetic fields; discuss thermomagnetic and galvanomagnetic phenomena in univalent metals at high temps and in semiconductors; compare the theory of elec phenomena in semiconductors with expts. Conclude that the urgent problem of analyzing the processes governing energy exchange of current-carriers with the lattice is more important than the new problems of statistically averaging quasi-particle parameters which are functions of temp. Cite 32 allied works (22 Soviet, 10 Western).

SAMOY LOVICH, A-G

SUBJECT USSR/MATHEMATICS/Statistics

CARD 1/1 PG - 62

AUTHOR TITLE SAMOJLOVIC A.G.

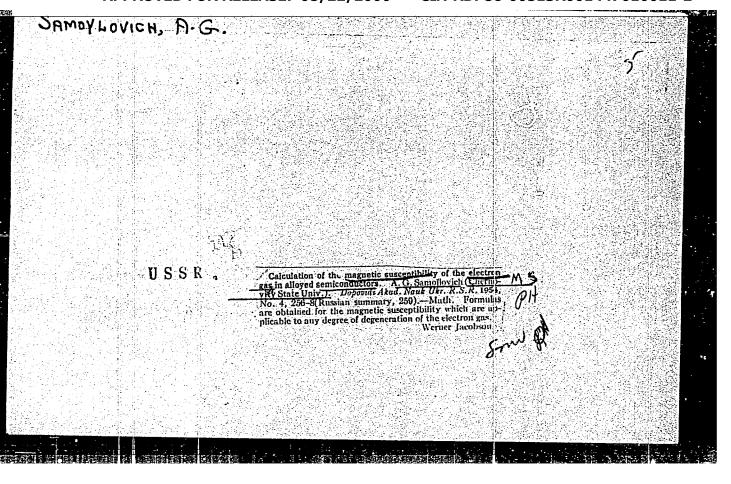
Statistics of the electrons in semi-conductors and canonical

distribution with variable number of particles.

PERIODICAL Dopovidi Akad. Nauk ukrain. RSR 3. 174-177 (1954)

reviwed 6/1956

The canonical distribution with variable number of particles is applied for deriving the equation which determines the chemical potential in the micture semi-conductor. It is shown that the formulas usually applied for calculating the chemical potential require the introduction of a correction, and this changes the condition for the appearance of the degeneration of the electron gas. The conditions for the appearance of the degeneration in mixture semi-conductors are determined.



SAMOYLOVICH, A.G.; KONONOVA, M.V.

Magnetic susceptibility of unalloyed semiconductors. Dop. AN URSR no.5:365-367 '54. (MIRA 8:7)

1. Chernivets'kiy derzhavniy universitet. Predstaviv diysniy chlen AN URSR V.E. Lashkar'ov. (Semiconductors-Magnetic properties)

SAMOYLOVICH, A.G.

CHAPTER THE PROPERTY OF THE PERSON OF THE PE

Hagnetic properties of semiconductors from the point of view of the zone theory. Dop. AN URSR no.5:368-370 154. (MIRA 8:7)

1. Chernivets'kiy derzhavniy universitet. Predstaviv diysniy chlen AN URSR V.E. Lashkar'ov. (Semiconductors—Magnetic properties)

SAMOYLOVICH

Call Nr: AF 1095038

AUTHOR:

Samoylovich, A. G.

TITLE:

Thermodynamics and Statistical Physics (Termodinamika i statisticheskaya fizika)

PUB. DATA:

Gosudarstvennoye izdatel styo tekhniko-teoreticheskoy literatury, Moscow, 1955, 2nd ed., 368 pp., 8,000 copies.

ORIG. AGENCY:

None

EDITOR:

Tkachuk, S.G., and Kuznetsova, Ye.B., Tech. Ed.

Tumarkina, N.A.; Ed. of the Publishing House: Gurov, K.P.

PURPOSE:

Approved by the Ministry of Higher Education as a textbook for state universities, this book is said to be the first complete text written for both parts of the course on thermodynamics and statistical physics.

COVERAGE:

See Table of Contents. The book deals with Russian contributions. There are 51 references, of which 40 are USSR, 1 German, and the remainder translations into

Russian. Personalities mentioned include: Korenblit, L.L.,

Card 1/10.

Candidate of Phys.-Math.Sciences, Chernovtsy State

SOV/58-59-5-10953

Translation from: Referativnyy Zhurnal Fizika, 1959, Nr 5, p 149 (USSR)

AUTHORS:

Samoylovich, A.G., Yakovlev, V.A.

TITLE:

The Kinetics of Semiconductor Photoconductivity

PERIODICAL:

Nauk. zap. Chernivets'k. un-t, 1955, Vol 12, pp 167 - 175 (Ukr.; Russ.

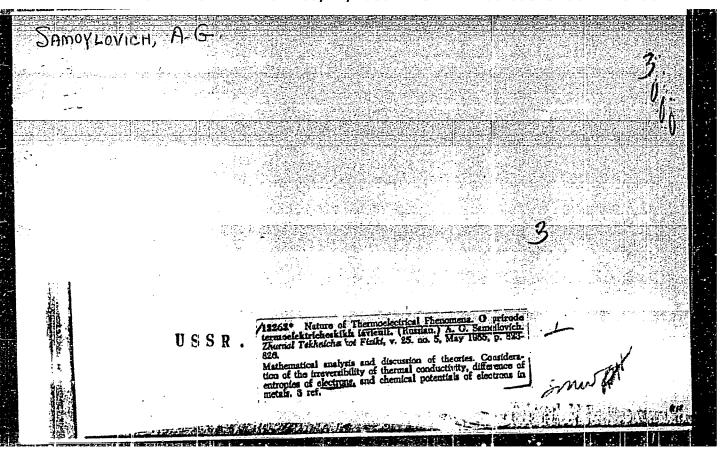
résumé)

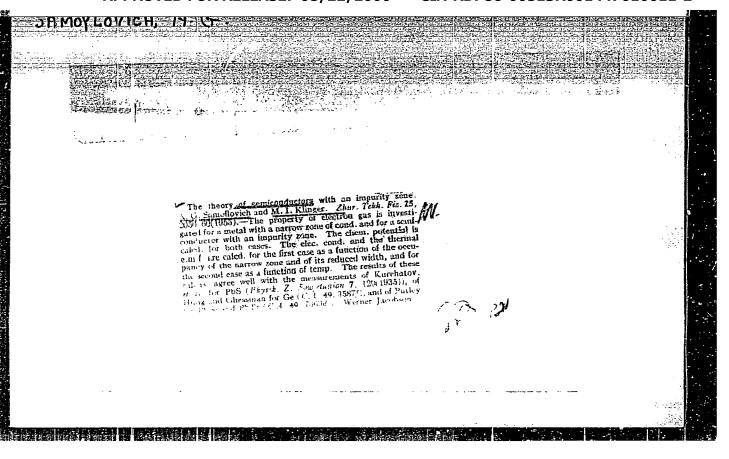
ABSTRACT:

The authors studied the character of photocurrent in relation to time as the light which illuminates the semiconductor is switched on and off. The introduction into the kinetic equation of a "statistical term" which takes the thermal interaction of the levels into account makes it possible, in the main, to explain the breaking up of semiconductors that Gurevich and Tolstoy propounded (Gurevich, Tolstoy, Dokl. AS USSR, 1950, Vol 72, p 473); namely, the hyperbolic or exponential character of the variation of the photocurrent is directly caused by the character of steady semiconductor photoconductivity. (Chernivetsk. un-t, USSR).

The authors' résumé

Card 1/1





SAMOTLOVICH, A.G.

"Semiconductors in modern physics". "Semiconductors" (popular science series). A.F. loffe. Reviewed by A.G. Samoilovich. Usp. fiz.nauk 57 no.1:165-169 S '55. (MIRA 9:1)

(Semiconductors) (Joffe, Abram Fedorovich, 1880-)

Category: USSR/Electricity - Semiconductors

Abs Jour : Ref Zhur - Fizika, No 1, 1957 No 1567

: Samoylovich, A.G., Korenblit, L.L.

Title

: Degeneracy of Electron Gas in Semiconductors

Orig Pub : Uspekhi fiz nauk, 1955, 57, No 4, 577-630

Abstract : A systematic discourse on various theoretical problems involved in the degeneracy of electrons and holes in semiconductors, the temperature dependence of the chemical potential, and the effect of the degeneracy on the magnetic properties and on the kinetic scattering coefficient of the electrons by the impurity ions. Bibliography, 42 titles.

Card : 1/1

SAMOYLOUICH, A.G.

USSR/ Physics - Excitons

Card 1/1

Pub. 22 - 11/50

Authora

s Samoylovich, A. G., and Korenblit, L. L.

WHEN THE PROPERTY OF THE PARTY OF THE PARTY

Mtle

Magnetic and optical characteristics of excitone

Periodical : DOK. AN SSSR 100/1, 43-44, Jan. 1, 1955

Abetract

: An exciton, defined as an electron and a hole connected together, is studied mathematically. The Hamiltonian function derived from a Lagrangian function, expressing the physical system of an excitone, is simplified and interpreted in the view of its magnetic and optical properties. Two USSR references (1949 and 1953).

Institution:

State University at Chernovitsy

Presented by:

Academician A. F. Ioffe, July 12, 1954

LOVICHA.O. SAMOY LOVICH, A. G. SAMOY PA - 1889

SAMOJLOVIC, A.G., KONDRATENKO, V.M. SUBJECT

On the Theory of Atomic Semiconductors. AUTHOR

Zurn.eksp.i teor.fis,31,fasc.4,596-608 (:956) TITLE

PERIODICAL

On the basis of the polar crystal model of VONSOVSKIJ several problems connected with the theory of the absorption of light and the theory of photoconductivity in atomic semiconductors are investigated in consideration of exitons. The exchange energy is neglected on this occasion, which leads to the degeneration of the lower energy band of the spectrum to an energy level. If the excitation energy of the exitons is greater than the initial energy of the current states, the states which correspond to the exitons and current states overlap. The paper begins with dealing with the basic features of the derivation of the HAMILTONIAN of the polar semiconductor model, on which occasion the well-known representation of the HAMILTONIAN by quantized wave functions serves as a starting basis. Also the expressions for the matrix elements are written down. The here mentioned expression for the HAMILTONIAN, which takes the exiton states into account, contains terms of the third order with respect to the operators of second quantization. This HAMILTONIAN is then transformed for the space of quasi-mementa; the necessary canonical transformation is written down. The HAMILTONIAN thus transformed can be written down as the sum of the energies of elementary excitations, and also the terms of the third order are written down. The physical significance of the individual terms of the third order is ex-

Zurn.eksp.i teor.fis, 31, fasc.4, 596-608 (1956) CMRD 2 / 2 plained, on which occasion the following processes are mentioned: Annihilation of a left exiton with transfer of its energy to a hole, creation of a left exiton at the expense of the kinetic energy of a hole, spontaneous annihilation of a right or of a left exiton with the simultaneous production of a pair and of a hole. There follow some remarks on the HAMILTONIAN of the external disturbance which may be expressed as follows by means of quartized wave functions: $H' = \int \Psi^+(x)U(\vec{r}, t) \Psi(x) dx$. Here $U(\vec{r}, t)$ denotes the operator of the external disturbance. By inserting the quantized wave functions and by summation aq₁ i₁s aq₂i₂s. is obtained. Here Uq₁i over the spins H' = denotes the matrix element of the operator U(r,t) and a and a denote the usual FERMI operators of second quantization for the production and annihilation respectively of an electron in the corresponding node. The HAMILTONIAN of the external disturbance contains terms which describe also complicated processes as e.g. the simultaneous absorption of light with excitation of an exiton and with scattering at the holes. Next, expressions for the probability of the decay of an exiton on an admixture with production of a pair and a hole is derived. In conclusion the kinetics of photoconductivity is computed.

INSTITUTION: State University of Cernovic

Szmoylovich, A.G.

AUTHORS TITLE Samoylovich, A.G., Tovstyuk, K.D. 57-8-15/36
The Energy Spectrum of Current Carriers in Semi-

conductors of the Germanium Type.

(Energeticheskiy spektr nositeley toka v poluprovodnikakh

tipa germaniya.)

PERIODICAL

Zhurnal Tekhn. Fiz., 1957, Vol. 27, Nr 8, pp.1753-1763

(USSR)

ABSTRACT

Here the authors try to combine two of the most important ideas of modern semiconductor theory: renunciation of the single-electron approach and the investigation of the problem from the point of view of the multi-electron theory within the frame of the quasi-particle method, and secondly the taking into account of the nature of chemical compound. A model is proposed which, on the occasion of the investigation of the energy spectrum, makes possible to respect the nature of the chemical compound. The authors show that the nodal lattice is essential for the electrons and the ruled lattice for the holes. The results of the investigations showed that it is just this with which the characteristic properties of electrons and holes in semiconductors of the Germanium type are connected. The energy spectrum of the current carriers in Germanium and Si is investigated. The authors show that the

CARD 1/2

57-8-15/36 The Energy Spectrum of Current Carriers in Semiconductors of the Germanium Type.

> characteristics of the energy spectrum of holes does not depend on the spinosorbital interaction but on the distribution of the clouds of valence-electrons, i.e. on the nature of the chemical compound. The authors show that by means of a corresponding selection of wave functions an electron spectrum coinciding with experimental data can be obtained.

(With 2 illustrations and 3 Slavic references)

ASSOCIATION: Chernovtsy State University.

(Chernovitskiy gosudarstvennyy universitet.)

SUBMITTED: AVAILABLE:

February 25, 1957 Library of Congress.

CARD 2/2

A Note on the Quantum Theory of the Kinetic Phenomena in Semiconductors.

57-12-1/19

was omitted here, because the investigation simed at purely methodical purposes. In the special cases investigated here, it was assumed, that the shape of the function $\mathcal{T}(H_0)$ is identical to that of \mathcal{T} (ξ) in the case of an absence of magnetic field. T denotes the relaxation period, Ho the operator of the "kinetic" energy of the particle in the magnetic field. For the sake of simplicity the tensorial character of the effective electron-mass was not taken into consideration. For this reason, in the case of several effects no anisotropy was obtained. The case of a mixed conductivity was also neglected. The essential result of this paper consists in showing, that the quantum corrections are of no great importance at helium-temperatures. A few longitudinal effects are of interest, which are missing in a semi-classical approximation. An investigation of these may permit the determination of the effective mass. In the case of an unipolar conductivity the investigation of these effects permits a selection of the receptivity of the current carriers in semiconductors. This idea was first pronounced by Ya. G. Dorfman (reference 7). The present

Card 2/5

57-12-1/19

A Note on the Quantum Theory of the Kinetic Phenomena in Semiconductors.

investigation was conducted in connection with it. As to details the distribution function operator is deduced here and the generalized laws for the electric and thermal conductivity are given. On the occasion of the investigation of the galvanic and thermomagnetic phenomena in ionsemiconductors it is pointed to the fact, that in the case of ion-semiconductors of the non-polar type the relaxation period of the current carriers may be considered to be independent from the energy and constant in the case of an interaction with the phonones. For the reason, that in such a case the computation of the kinetic coefficients is greatly simplified, it is here considered in the first instance. Two cases are considered here: Weak fields with $x \ll 1$ and strong fields with low temperatures and small effective masses $x \geq 1$. There follows the investigation of the galvanic and thermomagnetic phenomena in semiconductors of the atomic type, and of the kinetic phenomena in semiconductors at VT | E | R (longitudinal effects) and

Card 3/5

A Note on the Quantum Theory of the Kinetic Phenomena in Semiconductors.

57-12-1/19

finally the dependence of the chemical potential in semiconductors on the magnetic field. ${\mathcal X}$ denotes the magnetic field, which is assumed to be directed along the z-axis, and E the potential of the electric field. On the basis of the investigation conducted here the effects connected with the quantization of the paths and an evaluation of their magnitude are explained. The conclusion may be drawn, that the taking into consideration of the quantization of the paths of the current carriers in a magnetic field has a certain effect of such and such a degree on the magnitude of all known kinetic effects. In this case the quantity $f \mathcal{V}$ determining the ratio between the "zero" magnetic energy of the oscillators $\frac{1}{2}$ th ω_{o}^{*} and the average kinetic energy of the particles kT represents the essential parameter, which determines the effectiveness of the quantization of the energy-particle spectrum in the magnetic field. It is shown, that in the case of fy &1 the consideration of the quantization of the paths leads to only insignificant modifications of the ordinary formulae for the electric, thermoelectric and other effects. Only in the case of

Card 4/5

A Note on the Quantum Theory of the Kinetic Phenomena in Semiconductors.

57-12-1/19

f \lor 1 noticeable modifications may be expected. In general however, the quantity f \lor is comparatively small and varies between the values of 1/10 to 10. The evaluation given here has only a general character. The mobility of the current carriers also plays a certain role. There are 2 figures, 1 table, and 10 references, 5 of which are Slavic.

ASSOCIATION:

Institute for Semiconductors AN USSR, Leningrad (Institut

poluprovodnikov AN SSSR Leningrad).

SUBMITTED:

April 24, 1957.

AVAILABLE:

Library of Congress

Card 5/5

SAMOYLOVICH, A.G.

AUTHORS:

Samoylovich, A. G., Klinger, M. I.,

57-12-13/19

Nitsovich, V. M.

TITLE:

On the Correlation Between the Electrons in Narrow Admixture Zones of Semiconductors (O korrelyatsii mezhdu elektronami v uzkikh primesnykh zonakh poluprovodnikov).

PERIODICAL: Zhurnal Tekhnicheskoy Fiziki, 1957, Vol. 27, Nr 12,

pp. 2784-2785 (USSR)

ABSTRACT:

In this paper, the influence of the correlation between the electrons on the electron distribution in a narrow admixture zone and on the electron distribution according to quasi-momenta. The investigation is started from the assumtion, that only electrons situated in one admixture centre may interact with each other. From the result obtained, (equation) it can be seen, that in the case of $A^{4} = 0$ (no correlation) the ordinary statical formulae by Fermi-Dirac (with an exactitude including A#2) are obtained. In the case of A co, (infinite correlation, implying the absolute impossibility of finding two electrons in one admixture atom) a further formula is deduced from the former one. The formulae deduced here, show, that the correlation

Card 1/2

On the Correlation Between the Electrons in Narrow Admixture 57-12-13/19 Zones of Semiconductors

between the electrons leads to a considerable scattering of the electrons within the zone and promotes the occurrence degeneration. A more exact investigation of the influence of the correlation between electrons on the kinetics of processes in the narrow admixture zone will be conducted by V. M. Nitsovich in another place.

ASSOCIATION: Institute for Semiconductors AN USSR, Leningrad

(Institut poluprovodnikov AN SSSR Leningrad)

SUBMITTED: March 27, 1957

AVAILABLE: Library of Congress

Card 2/2

"APPROVED FOR RELEASE: 08/22/2000

CIA-RDP86-00513R001447010011-2

AUTHOR TITLE SAMOYLOVICH, A.G.

53-3-8/:0

Diffe, A.F., Stil bans, L.S., Tordanishvilli, Ye.K., Stavitskeya, T.S., Thermoelectric Refrigeration". (Publishing House of the Academy of Science, Moscow-Leningrad, 1956, p.108, 3,70 Rb.)

(Toffe, A.F., et al. "Termoelektricherkoye hhlaz'den: (Russian) Uspekhi Fiz. Nauk, 1957, Vol 62, Nr 3, pp 375 - 376 (U.S.S.R.)

PER IODICAL

ABSTRACT

The book consists of three chapters dealing with refrigeration by thermoelectric means, giving theoretical and experimental data. In chapter 1. the theory of thermoelectric refrigeration is developed. Further, the efficiency of a cascade battery is calculated and it is shown that more than two steps are useless.

Chapter 2. "The experimental investigations of thermoelectric properties of semiconductors" above all describes and evaluates the methods for measuring the Peltier and Thompson coefficients, the EMF, the electric conductivity, etc. The thermoelectric properties of the best initial material for a thermoelement FbTe — FbSe are most thoroughly treated.

Chapter 3. deals with the application of thermoelectric refrigeration. It is already today possible to construct household refrigerators with thermoelements, which are more economical than absorption refrigerators.

Card 1/2

53-3-8/10

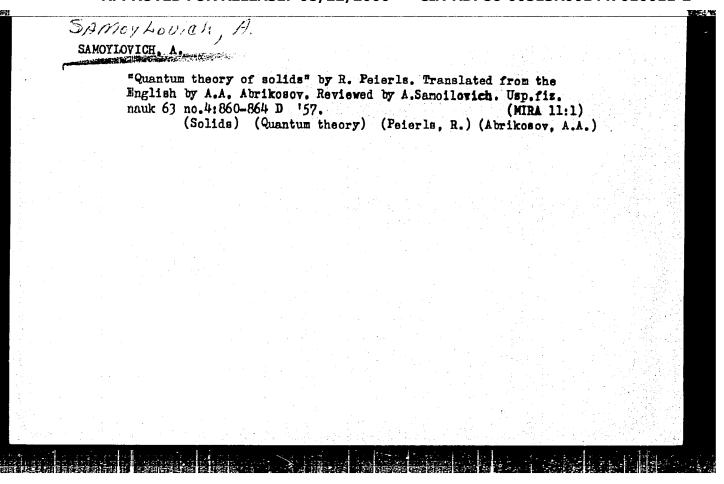
Toffe, A.F., Stillbans, L.S., Iordanis willi, Ye.G., Stavitskaya, T.S., Thermoelectric Refrigeration. (Publishing House of the Academy of Science, Moscow-Leningrad, 1956, p.108, 3,70 Rb.)

The book which is written in clear language and is very well subdivided may be of use for physicists, chemists and refrigeration engineers.

ASSOCIATION PRESENTED BY SUBMITTED AVAILABLE Not given

Library of Congress

Card 2/2



SAMOYLOVICH, A.G. [Samoylovych, A.H.]; KONDRATENKO, V.M.

On the theory of atomic semiconductors. Part 1. Derivation of the hamiltonian of an atomic semiconductor in a polar crystal model [In Ukrainian with summary in English]. Ukr.fiz.zhur. 3 no.1:41-52 Ja-F '58.

(MIRA 11:4)

1. Chernivets'kiy derzhavniy universitet.

(Semiconductors) (Excitons)

24(3) SOV/20-123-5-16/50

AUTHORS: Samoylovich, A. G., Korenblit, L. L.

TITLE: The Faraday Effect on Mott's Excitons (Effekt Faradeya na

eksitonakh Motta)

PERIODICAL: Doklady Akademii nauk SSSR, 1958, Vol 123, Nr 5, pp 828-831

(USSR)

ABSTRACT: This paper deals with the Faraday (Faradey) effect on Mott's

excitons of not too great radii ($d < 10^{-5}$ cm). The Verde constant can be determined on the basis of their connection with the vector of gyration, and the problem is therefore reduced to the calculation of the complex polarizability of the exciton. This exciton is subjected to the influence of the constant magnetic field \hat{H} , and of a monochromatic electro-

magnetic wave of the frequency , and of the vector potential $\vec{A}(\vec{\xi})$ Re \vec{A}_0 e \vec{b} \vec{b} \vec{c} \vec{c}

vector. The medium is assumed to be isotropic. After the introduction of new denotations, an expression is given for the Hamiltonian of the exciton. This Hamiltonian can be simplified noticeably in the case of dipole approximation.

Card 1/2 The authors then solve the time-dependent Schroedinger

The Faraday Effect on Mott's Excitons

SOV/20-123-5-16/50

(Shredinger) equation. The state of the exciton (for A=0) can be described by the whole of the integrals of motion. The authors then discuss step by step the deduction of the tensor of polarizability. An expression is found also for the vector of gyration. This vector of gyration is proportional to the difference Δ of the masses of the electron and of the hole. According to the results of this paper, a Faraday effect on excitons is possible only in the case $m_e \neq m_h$. In this case the rotations of the polarization plane which are caused by the electron and by the hole completely compensate one another. (m_e^* and m_h^* denote the effective mass of the electron and of the hole, respectively). There are 4 Soviet references.

ASSOCIATION: Institut poluprovodnikov Akademii nauk SSSR (Institute of Semi-

conductors of the Academy of Sciences, USSR)

PRESENTED: August 6, 1958, by A. F. Ioffe, Academician

SUBMITTED: August 1, 1958

Card 2/2

663340

24(3) 24.7700

SOV/181-1-10-15/21

AUTHORS:

Samoylovich, A. G., Korolyuk, S. L.

TITLE:

The Theory of Elementary Excitation in Atomic Semiconductors

PERIODICAL:

Fizika tverdogo tela, 1959, Vol 1, Nr 10,

pp 1592 - 1599 (USSR)

ABSTRACT:

A. F. Ioffe assumed in a paper (Ref 2) that in semiconductors excitons participate in the thermal conduction. The excitons may now be assumed to play a part in kinetic phenomena also as scattering centers of electrons and holes. The authors of the present paper investigate the interactions of electrons and holes with excitons, of excitons with phonons, etc. This is possible in the simplest way by considering electrons, excitons, and holes as elementary excitations in the crystal, which may interact among one another (cf. Refs 1-9). For a detailed investigation of kinetic phenomena it is necessary to have a Hamiltonian, which describes the behavior of semiconductors from the point of view of elementary excitations in consideration of interactions between them. Such a Hamiltonian was deduced in reference 10, but is was found to be incomplete,

Card 1/3

663340

The Theory of Elementary Excitation in Atomic Semiconductors

SOV/181-1-10-15/21

because some important terms describing interaction among elementary excitations were lacking. It was the task of the present paper to set up such a complete Hamiltonian. One of the most important tasks to be performed was to exclude the "background", i.e. the regular separation of the ground state (cf. Refs 5-8). Interactions were taken into account according to a method by Bonch-Bruyevich (Ref. 1), which was somewhat varied for the case under investigation. The simple model of an atomic semiconductor is investigated, where every atom has a saturated valence shell with two electrons. The following elementary excitations may occur: Electrons, holes, ortho- and paraexci-The method of expanding the Hamiltonian is discussed in detail, and the quadratic terms occurring therein (systems (6) - (8)) are explicitly written down. Finally, also the Hamiltonians of third and fourth order are given, and individual terms, which describe special forms of interaction, (e.g. electrostatic interaction between the elementary excitations in the $\Re(4)$: formula (26), electrostatic interaction between holes and electrons: (27), between excitons and holes and electrons: (28)) are written down. There are 12 references, 11 of which

Card 2/3

"APPROVED FOR RELEASE: 08/22/2000

CIA-RDP86-00513R001447010011-2

The Theory of Elementary Excitation in Atomic Semiconductors

SOV/181-1-10-15/21

are Soviet.

ASSOCIATION:

Institut poluprovodnikov AN SSSR Leningrad (Institute for Semiconductors, AS USSR, Leningrad). Chernovitskiy gosudarstvennyy

universitet (Chernovtsy State University)

SUBMITTED:

February 20, 1959

Card 3/3

81782 S/181/60/002/02/30/033 B006/B067

24,7900 AUTHORS:

Samoylovich, A. G., Nitsovich, M. V.

TITLE:

The Problem of Magnetic Susceptibility of Metallic Lithium

PERIODICAL: Fizika tverdogo tela, 1960, Vol. 2, No. 2, pp. 371-373

TEXT: The present article is a continuation of a previous paper (Ref. 1) in which general expressions were deduced for the orbital magnetic susceptibility of an electron gas in a crystal. These expressions are here employed for calculating the magnetic susceptibility of metallic lithium. Pines (Ref. 2) has already analyzed the experimental data obtained for lithium, and he represented them theoretically by the formula $\chi_0 = \chi_s + \chi_d + \chi_a$; here, χ_0 denotes the total magnetic susceptibility, χ_s the paramagnetic spin susceptibility with regard to electronic interaction, χ_a the atomic diamagnetic susceptibility, and χ_d the diamagnetic susceptibility of the conduction electrons. The author now attempts to give a better description of the experiments, and he demonstrates his method by the example of lithium. He sets $\chi = \chi_1 + \chi_2 + \chi_3 + \chi_4 + \chi_5$ for

Card 1/2

* Fizika metallov i metallovedeniye, 1959, Vol.7, Nr. 5, pp 641-649 (USSR)

The Problem of Magnetic Susceptibility of Metallic Lithium

81782 \$/181/60/002/02/30/033 B006/B067

its susceptibility (it has a body-centered cubic lattice). χ_i is given by formulas (3) - (7), where the denotation introduced in Ref. 1 is used. These terms are calculated by the approximation method of Bardeen, A. G. Samoylovich, and V. Barkhatov. The results are discussed for each term individually. The following was obtained: The main portion of diamagnetic susceptibility is represented by χ_1 ; it was found that $\chi_1 = -0.148$; $\chi_2 = -0.025$; $\chi_3 + \chi_4 = -0.121$, which indicates the strong coupling of conduction electrons in lithium; $\chi_d = \chi_1 + \chi_2 + \chi_3 + \chi_4 = -0.294$; $\chi_5 = 0.0171 \frac{\alpha}{|\Delta E|}$, $\alpha = 15.2$ ev, $|\Delta E| = 0.52$ ev. In conclusion, the author thanks L. L. Korenblit for discussions. There are 2 tables and 4 references: 3 Soviet and 1 American.

ASSOCIATION: Institut fiziki poluprovodnikov AN SSSR (Institute of Semiconductor Physics of the AS USSR). Chernovitskiy gosudarstvennyy universitet (Chernovitsy State University)

SUBMITTED: September 12, 1959

Card 2/2

X

24,7600 (1035,1043,1144)

S/181/60/002/011/024/042 B006/B056

AUTHORS:

Same vlovich, A. G. and Iskra, V. D.

TITLE:

Effect of Crystal Anisotropy Upon Thermal Vibrations of

Atoms in Ge and Si

PERIODICAL:

Fizika tverdogo tela, 1960, Vol. 2, No. 11, pp. 2827-2833

TEXT: The present paper describes a theoretical study of the spectrum and polarization of acoustic phonons in germanium and silicon. It is shown that the anisotropic crystal of Ge or Si, which is characterized by the elastic moduli c_{11} , c_{12} , and c_{44} ($c^* = -c_{11} + c_{12} + 2c_{44} \neq 0$), may well be replaced by an elastic and isotropic crystal whose elastic moduli are de-

$$c_{44}^{!} = \frac{1}{5} \left\{ 2c_{44} + c_{11} - (c_{11} - c_{44}) \sqrt{1 + \frac{3 c^{*}(c_{11}^{+c_{12}})}{5(c_{11} - c_{44})^{2}}} \right\}, c^{*!} = 0.$$

86437

Effect of Crystal Anisotropy Upon Thermal Vibrations of Atoms in Ge and Si

S/181/60/002/011/024/042 B006/B056

The constants have the following numerical values:

	_	^C 12	^C 44	c ₁₁	c T	°11	C ₄₄
Ge	$\left[10^{12} \text{dyn/cm}^2\right]$	0.53	0.68	1.356	0.534	1.592	0.562
Si	$\left[10^{12} \text{dyn/cm}^2\right]$	0.65	0.801	1.675	0.577	1.927	0.675

The spectrum of accustic phonons is given as

$$\omega_{1} = \sqrt{\frac{c_{44}}{\varrho}} \left(k^{2} + \frac{b}{3} + \frac{2b}{3} \sqrt{1 - 3\frac{c^{1}}{\varrho^{2}}}\right); \quad \omega_{2,3} = \sqrt{\frac{c_{44}}{\varrho}} \left(k^{2} + \frac{b}{3} - \frac{b}{3} \sqrt{1 - 3\frac{c}{\varrho^{2}}}\right).$$
For Ge, $b = \frac{c_{11} - c_{44}}{c_{44}} k^{2} = 0.994k^{2}$ and $c = -\frac{c * (c_{11} + c_{12})}{c_{44}^{3}} f = -2.178 f;$

for Si, b = $1.091k^2$ and c = -2.091 f. As ω_1 and ω_2 depend only little on the direction of the wave vector k, it is possible to average over the directions of k by putting $\xi = 1/5$. It can be shown that the polarizations of oscillations differ only little from those observed in an isotropic crystal. There are 4 figures, 2 tables, and 6 references: 2 Soviet and Card 2/3

86437

Effect of Crystal Anisotropy Upon Thermal

S/181/60/002/011/024/042 B006/B056

Vibrations of Atoms in Ge and Si

4 US.

ASSOCIATION:

Institut poluprovodnikov AN SSSR Leningrad (Institute of Semiconductors of the AS USSR, Leningrad)

SUBMITTED:

July 10, 1960

Card 3/3